

9.2.6.1 Output Voltage Start-up Behavior

The start-up behavior of each rail was measured using resistive loads on the outputs. Figure 32 shows the start-up behavior of the 1V2, 2V5, 3V3 and 5V rails whilst Figure 33 shows the 6V6 and 12V rails with the 1V2 start-up as a reference.

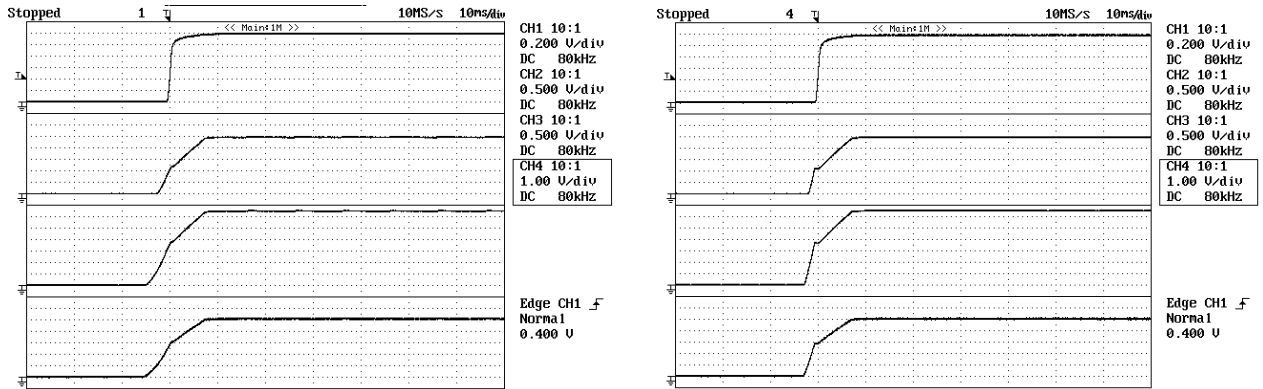


Figure 32 - Start-up Behavior of 1V2 (Top 0.2V/div), 2V5 (Second From Top 0.5V/div), 3V3 (Third from Top 0.5V/div), 5V (Bottom 1V/div). Left Hand Side is 85V_{ac} input and Right Hand Side is 265V_{ac}. Timebase is 10ms/div

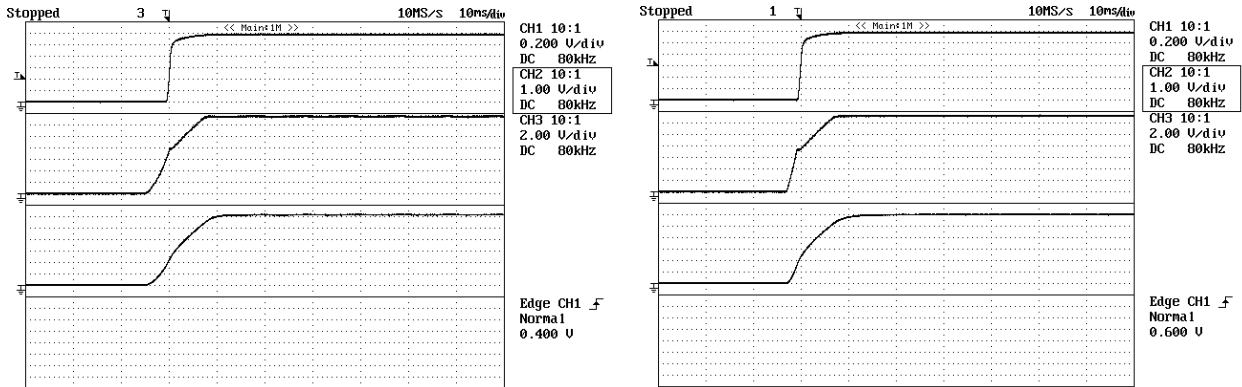


Figure 33 - Start-up Behavior of 1V2 (Top 0.2V/div), 6V6 (Second From Top 1V/div), 12V (Bottom 2V/div). Left Hand Side is 85V_{ac} input and Right Hand Side is 265V_{ac}. Timebase is 10ms/div

All rails start-up within 10ms and have zero voltage overshoot.



9.2.6.2 Measured Noise and Ripple

All waveforms were measured with 115V mains input and at full operating power. All results AC coupled.

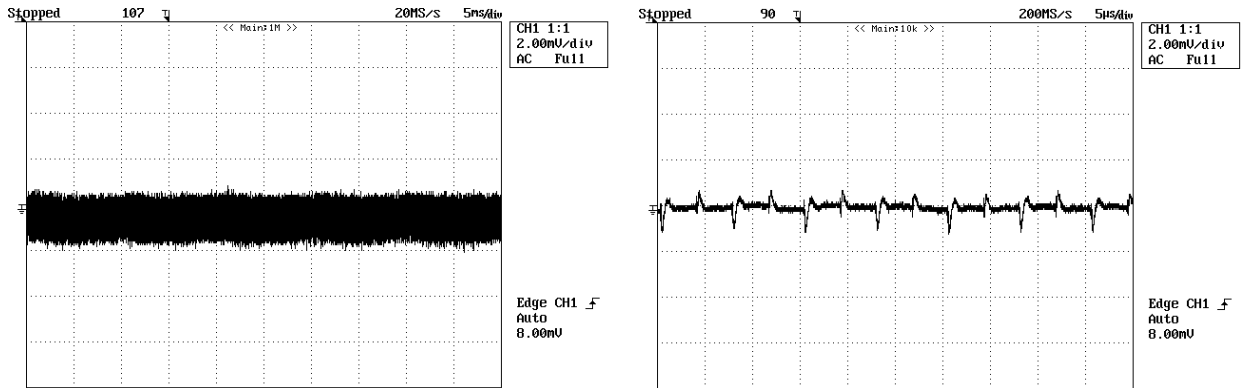


Figure 34 – 1V2 Rail. Output 100Hz ripple (LHS, 5ms/div and 2mV/div) and 132kHz noise (RHS, 5us/div and 2mV/div)

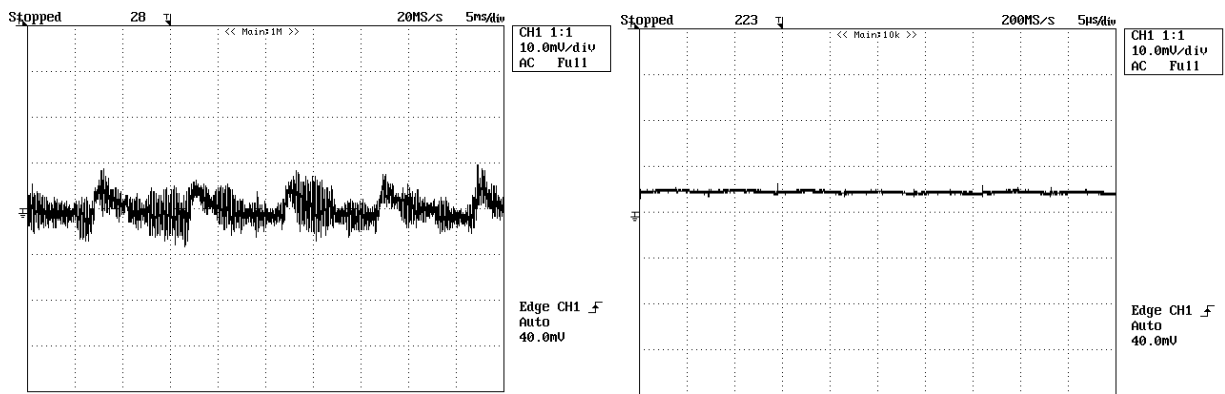


Figure 35 – 2V5 Rail. Output 100Hz ripple (LHS, 5ms/div and 10mV/div) and 132kHz noise (RHS, 5us/div and 10mV/div)

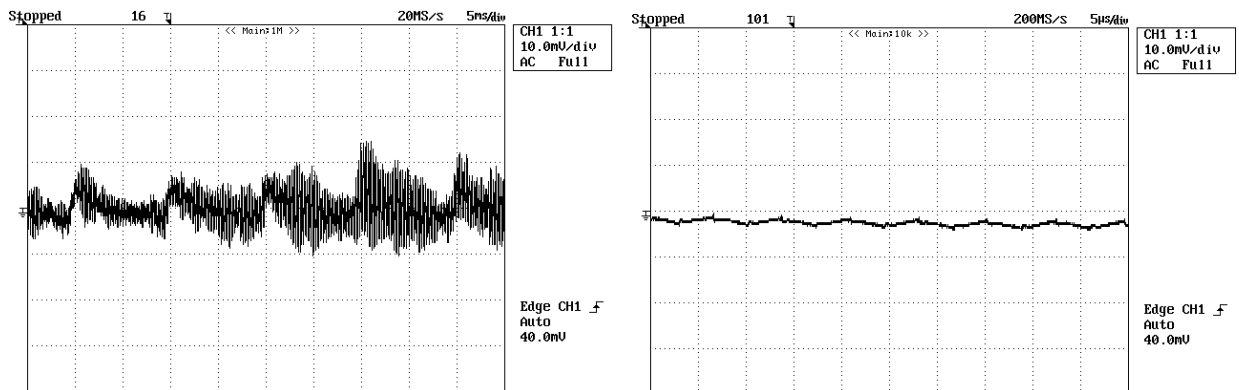


Figure 36 – 3V3 Rail. Output 100Hz ripple (LHS, 5ms/div and 10mV/div) and 132kHz noise (RHS, 5us/div and 10mV/div)



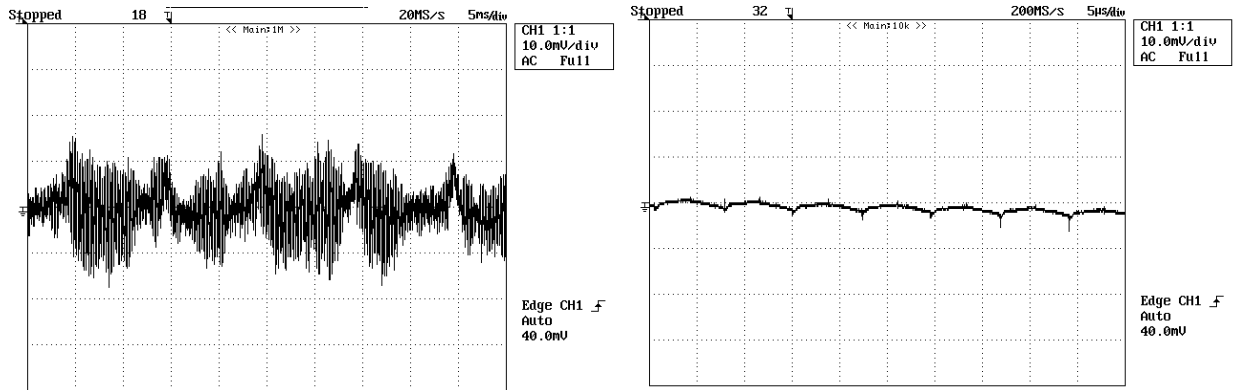


Figure 37 – 5V Rail. Output 100Hz ripple (LHS, 5ms/div and 10mV/div) and 132kHz noise (RHS, 5us/div and 10mV/div)

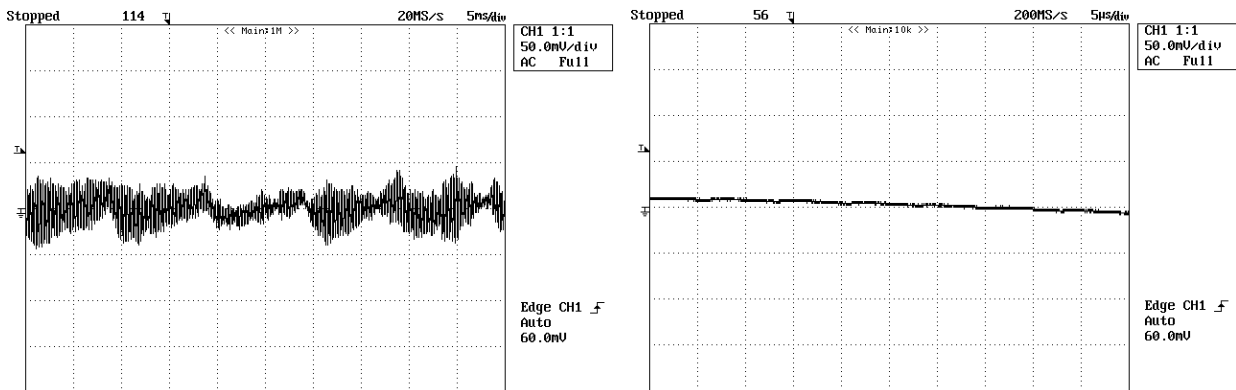


Figure 38 – 6V6 Rail. Output 100Hz ripple (LHS, 5ms/div and 50mV/div) and 132kHz noise (RHS, 5us/div and 50mV/div)

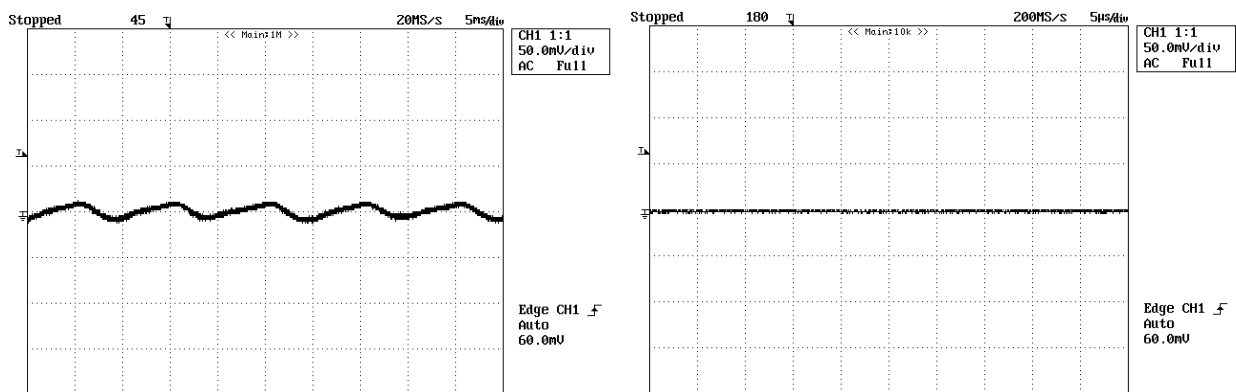


Figure 39 – 12V Rail. Output 100Hz ripple (LHS, 5ms/div and 50mV/div) and 132kHz noise (RHS, 5us/div and 50mV/div)



9.2.6.3 Transient Loading

In order to give an indication of loop stability, the load on the 3V3 rail was switched from 50% to 100% and the response of the rail measured. Figure 40 shows the results at $85V_{ac}$ and $265V_{ac}$.

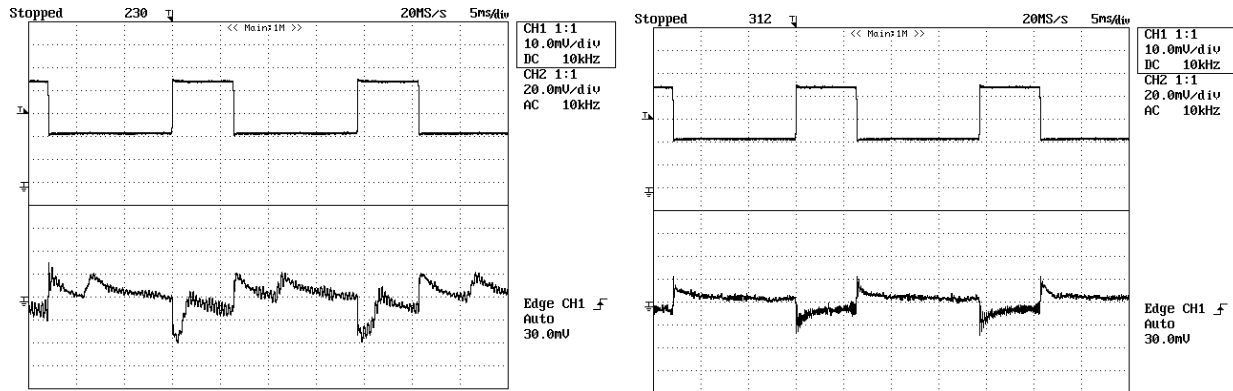


Figure 40 – Transient response on 3V3 rail. Upper is rail current at 0.1A/div and lower is AC coupled rail voltage at 20mV/div. Left Hand Side is $85V_{ac}$ input and Right Hand Side is $265V_{ac}$.

The voltage response shows a well damped behavior which indicates a good phase/gain margin. For production verification, a network analyzer should be used to measure the control loop response at extremes of load, line voltage and operating temperature. In the measurement of with $85V_{AC}$ input, there is a small component of ripple due to 100Hz breakthrough which shows up in the transient response plot. The level is very low and completely independent of the transient recovery behavior.



9.2.7 Conducted EMI Measurements

The measurements presented in this section are pre-compliance and should only be used for guidance. Measurements are performed with 115V input and full power output. Figure 41 gives the conducted EMI measurement with the output floating and Figure 42 with the output grounded to protective earth to simulate grounding through a SCART lead.

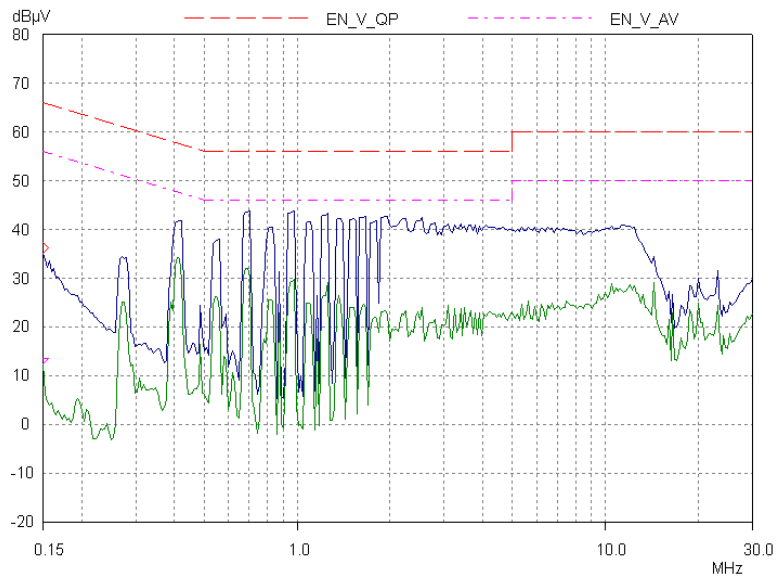


Figure 41 - EMI with Output Floating

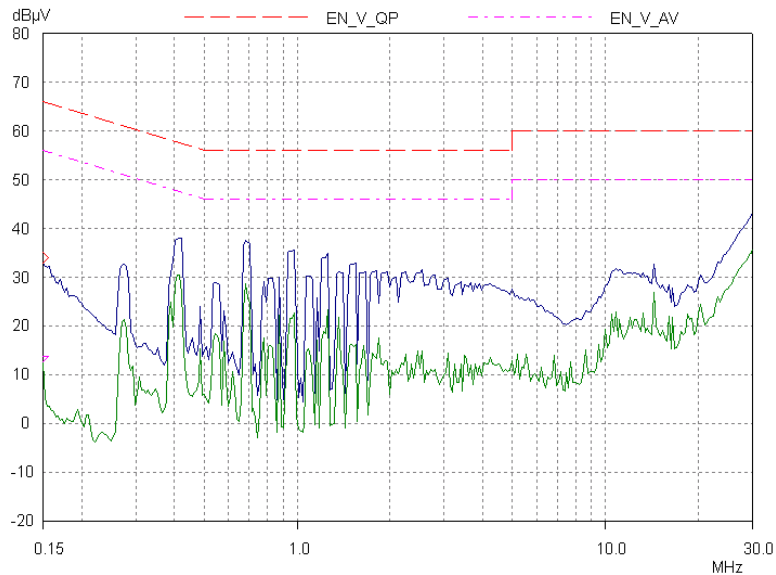


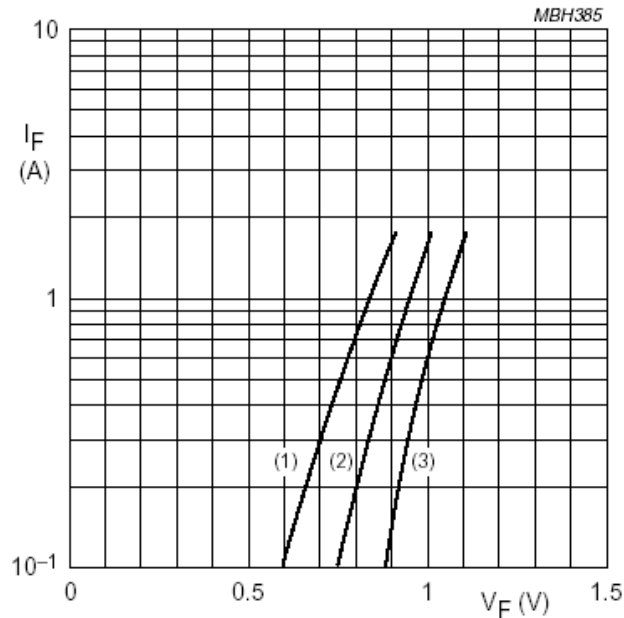
Figure 42 - EMI with Output Grounded to Protective Earth



10 Appendix A – Tolerance of Linear Regulated Outputs

10.1 2V5 Linear Regulated Output

The 2V5 output is provided via a diode drop from the 3V3 rail. The diode forward voltage will be a function of both diode current and temperature.



- (1) $T_{amb} = 100\text{ }^{\circ}\text{C}$.
- (2) $T_{amb} = 20\text{ }^{\circ}\text{C}$.
- (3) $T_{amb} = -50\text{ }^{\circ}\text{C}$.

Figure 43 – 1N4005 Diode Forward Voltage Behavior [Source - Philips Semiconductors]

The load current will vary from 30mA to 215mA and this will give a variation in diode drop of 0.7V to around 0.8V respectively. At 215mA and 20°C, the required 0.8V drop will be achieved giving 2.5V output.

With an operating ambient of 0-50°C, the likely diode temperature will be between 50°C and 100°C and therefore the voltage-current curve will lie between lines 1 and 2 on Figure 43.



10.2 1V2 Discrete Linear Regulator

The 1V2 linear regulator uses the circuit shown below to drop to 1.2V from 3.3V.

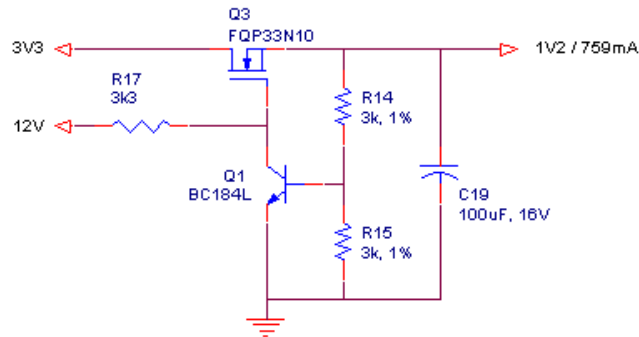


Figure 44 - 1V2 Discrete Linear Regulator

This circuit uses the base-emitter (V_{be}) voltage of Q1 to set the output voltage via R15 and R14. V_{be} is determined by the device temperature and the collector bias current. Pspice was used to simulate the variation of base-emitter voltage with collector current at 0, 25 and 50°C. The results are given in Figure 45 below.

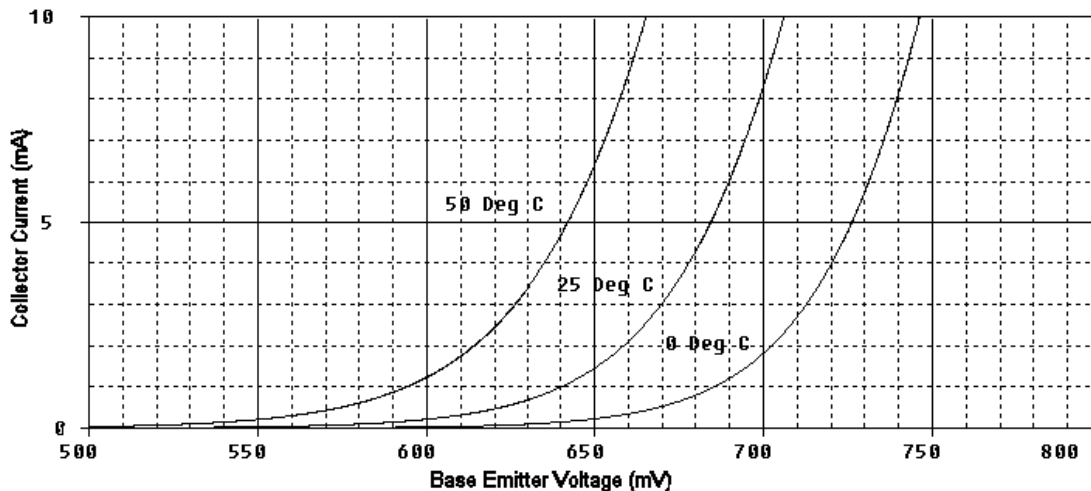


Figure 45 - Simulation of base-emitter voltage variation

Collector current in Q1 can be found from -
$$I_C = \frac{V_{Bias} - (V_{GS} + 1.2)}{R_{17}}$$

V_{BIAS} = Bias Voltage for Regulator (6.6V nominal here)

V_{GS} = Gate-Source voltage of Q3

Therefore, the collector current will vary with V_{BIAS} , V_{GS} and R_{17} . Differentiation of the I_C expression with respect to each of the three quantities will give the dependency.



$$\frac{dI_C}{dV_{BIAS}} = \frac{1}{R_{17}}, \quad \frac{dI_C}{dV_{GS}} = -\frac{1}{R_{17}} \quad \text{and} \quad \frac{dI_C}{dR_{17}} = \frac{-(V_{BIAS} - (V_{GS} + 1.2))}{(R_{17})^2}$$

With the values chosen,

$$\frac{dI_C}{dV_{BIAS}} = 0.3\text{mA/V}$$

$$\frac{dI_C}{dV_{GS}} = -0.3\text{mA/V}$$

$$\frac{dI_C}{dR_{17}} = -0.6\mu\text{A/V}$$

Thus, the two dominant mechanisms affecting the 1.2V output are variations in the regulator bias voltage (12V) and variations in the Gate-Source voltage of Q3. The bias voltage tolerance is 10% and this will give $\pm 0.36\text{mA}$ variation in collector current. The gate-source voltage behaviour of Q3 is shown below.

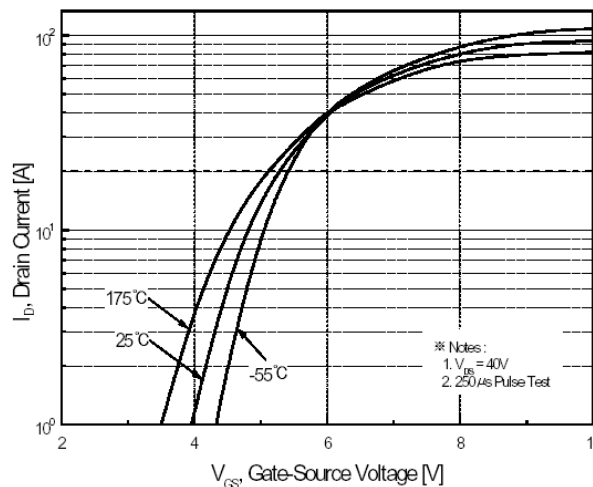


Figure 46 - Gate-Source Voltage Behaviour of QFP33N10

Figure 46 indicates that the gate-source voltage will vary by a maximum of around 0.5V over variations in temperature and drain current (0 to 1A). Thus, variations in the collector current of Q1 due to changes in the gate-source voltage of Q3 will be around $\pm 0.15\text{mA}$. The combined changes in collector current will be $\pm 0.45\text{mA}$ and this will have a very small effect on output voltage. Temperature changes will influence V_{BE} to a greater effect and Figure 45 shows V_{BE} changes from 715mV at 0°C and 2mA to 615mV at 50°C and 2mA. This gives an output voltage from the linear regulator circuit of 1.3V at 0°C and 1.12V at 50°C.



11 Revision History

Date	Author	Revision	Description & changes	Reviewed
March 30, 2004	IM	1.0	Initial release	VC / AM



For the latest updates, visit our Web site: www.powerint.com

Power Integrations reserves the right to make changes to its products at any time to improve reliability or manufacturability. Power Integrations does not assume any liability arising from the use of any device or circuit described herein, nor does it convey any license under its patent rights or the rights of others.

The products and applications illustrated herein (including circuits external to the products and transformer construction) may be covered by one or more U.S. and foreign patents or potentially by pending U.S. and foreign patent applications assigned to Power Integrations. A complete list of Power Integrations' patents may be found at www.powerint.com.

The PI Logo, **TOPSwitch**, **TinySwitch**, **LinkSwitch**, and **EcoSmart** are registered trademarks of Power Integrations. **PI Expert** and **DPA-Switch** are trademarks of Power Integrations.
© Copyright 2003, Power Integrations.

WORLD HEADQUARTERS

Power Integrations
5245 Hellyer Avenue,
San Jose, CA 95138, USA
Main: +1-408-414-9200
Customer Service:
Phone: +1-408-414-9665
Fax: +1-408-414-9765
e-mail:
usasales@powerint.com

AMERICAS

Power Integrations, Inc.
4335 South Lee Street,
Suite G,
Buford, GA 30518, USA
Phone: +1-678-714-6033
Fax: +1-678-714-6012
e-mail:
usasales@powerint.com

CHINA (SHANGHAI)

Power Integrations
International Holdings, Inc.
Rm 807, Pacheer,
Commercial Centre,
555 Nanjing West Road,
Shanghai, 200041, China
Phone: +86-21-6215-5548
Fax: +86-21-6215-2468
e-mail:
chinasales@powerint.com

APPLICATIONS HOTLINE

World Wide +1-408-414-9660

CHINA (SHENZHEN)

Power Integrations
International Holdings, Inc.
Rm# 1705, Bao Hua Bldg.
1016 Hua Qiang Bei Lu,
Shenzhen, Guangdong,
518031, China
Phone: +86-755-8367-5143
Fax: +86-755-8377-9610
e-mail: chinasales@powerint.com

GERMANY

Power Integrations, GmbH
Rueckerstrasse 3,
D-80336, Munich, Germany
Phone: +49-895-527-3910
Fax: +49-895-527-3920
e-mail: eurosales@powerint.com

INDIA (TECHNICAL SUPPORT)

Innovatech
261/A, Ground Floor
7th Main, 17th Cross,
Sadashivanagar
Bangalore, India, 560080
Phone: +91-80-5113-8020
Fax: +91-80-5113-8023
e-mail: indiasales@powerint.com

APPLICATIONS FAX

World Wide +1-408-414-9760

ITALY

Power Integrations s.r.l.
Via Vittorio Veneto 12,
Bresso, Milano,
20091, Italy
Phone: +39-028-928-6001
Fax: +39-028-928-6009
e-mail:
eurosales@powerint.com

JAPAN

Power Integrations, K.K.
Keihin-Tatemono 1st Bldg.
12-20 Shin-Yokohama,
2-Chome,
Kohoku-ku, Yokohama-shi,
Kanagawa 222-0033, Japan
Phone: +81-45-471-1021
Fax: +81-45-471-3717
e-mail:
japansales@powerint.com

KOREA

Power Integrations
International Holdings, Inc.
8th Floor, DongSung Bldg.
17-8 Yoido-dong,
Youngdeungpo-gu,
Seoul, 150-874, Korea
Phone: +82-2-782-2840
Fax: +82-2-782-4427
e-mail:
koreasales@powerint.com

SINGAPORE (ASIA PACIFIC HEADQUARTERS)

Power Integrations, Singapore
51 Newton Road,
#15-08/10 Goldhill Plaza,
Singapore, 308900
Phone: +65-6358-2160
Fax: +65-6358-2015
e-mail:
singaporesales@powerint.com

TAIWAN

Power Integrations
International Holdings, Inc.
17F-3, No. 510,
Chung Hsiao E. Rd., Sec. 5,
Taipei, Taiwan 110, R.O.C.
Phone: +886-2-2727-1221
Fax: +886-2-2727-1223
e-mail:
taiwansales@powerint.com

UK (EUROPE & AFRICA HEADQUARTERS)

1st Floor, St. James's House
East Street
Farnham, Surrey GU9 7TJ
United Kingdom
Phone: +44-1252-730-140
Fax: +44-1252-727-689
e-mail: eurosales@powerint.com

